

**CFSH01-30**  
**SURFACE MOUNT**  
**SILICON SCHOTTKY DIODE**



[www.centrasemi.com](http://www.centrasemi.com)

**TLP**™  
Tiny  
Leadless  
Package



Top View    Bottom View

**SOD-882L CASE**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CFSH01-30 is a high quality Schottky Diode designed for applications where ultra small size and low leakage current are prime requirements. Packaged in a Tiny Leadless Package™, TLP™, this component provides performance characteristics suitable for the most demanding size constrained applications.

**MARKING CODE: Z**

**APPLICATIONS:**

- DC - DC Converters
- Voltage Clamping
- Protection Circuits
- Battery powered applications including Cell Phones, Digital Cameras, Pagers, PDAs, Laptop Computers, etc.

**FEATURES:**

- Current ( $I_O=100\text{mA}$ )
- Very Low Reverse Current (30nA TYP @ 10V)
- Low Forward Voltage Drop ( $V_F=0.41\text{V}$  TYP @ 10mA)
- Small, Ultra Low Profile 1.0mm x 0.6mm x 0.4mm TLP™ Leadless Surface Mount package

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Peak Repetitive Reverse Voltage	$V_{RRM}$	30	V
Average Forward Current	$I_O$	100	mA
Peak Forward Surge Current, $t_p=8.3\text{ms}$	$I_{FSM}$	500	mA
Power Dissipation	$P_D$	100	mW
Operating Junction Temperature	$T_J$	-65 to +125	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +150	$^\circ\text{C}$
Thermal Resistance	$\theta_{JA}$	1000	$^\circ\text{C}/\text{W}$

**SYMBOL**

SYMBOL	MIN	TYP	MAX	UNITS
$V_{RRM}$		30	300	V
$I_O$		100	300	mA
$I_{FSM}$	30	500	500	mA
$P_D$		100	100	mW
$T_J$	-65 to +125			$^\circ\text{C}$
$T_{stg}$	-65 to +150			$^\circ\text{C}$
$\theta_{JA}$		1000		$^\circ\text{C}/\text{W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

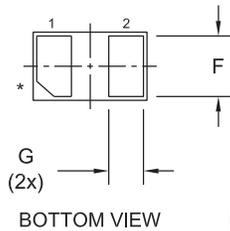
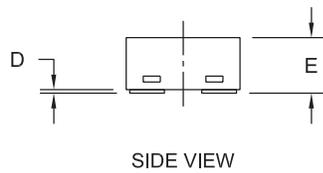
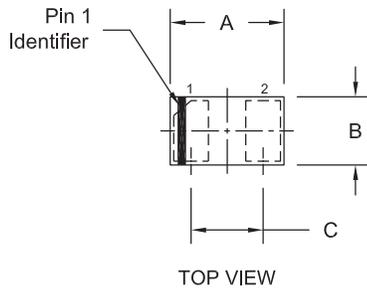
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_R$	$V_R=10\text{V}$		30	300	nA
$BV_R$	$I_R=100\mu\text{A}$	30			V
$V_F$	$I_F=10\text{mA}$		0.41	0.46	V
$C_T$	$V_R=0, f=1.0\text{MHz}$		7.0		pF

R0 (9-May 2011)

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**SOD-882L CASE - MECHANICAL OUTLINE**



\* Pin 1 chamfer may appear on any corner.

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.037	0.041	0.95	1.05
B	0.022	0.026	0.55	0.65
C	0.026		0.65	
D	0.000	0.002	0.00	0.05
E	0.012	0.016	0.30	0.40
F	0.018	0.022	0.45	0.55
G	0.008	0.012	0.20	0.30

SOD-882L (REV:R2)

**LEAD CODE:**

- 1) Cathode
- 2) Anode

**MARKING CODE: Z**

R2

R0 (9-May 2011)